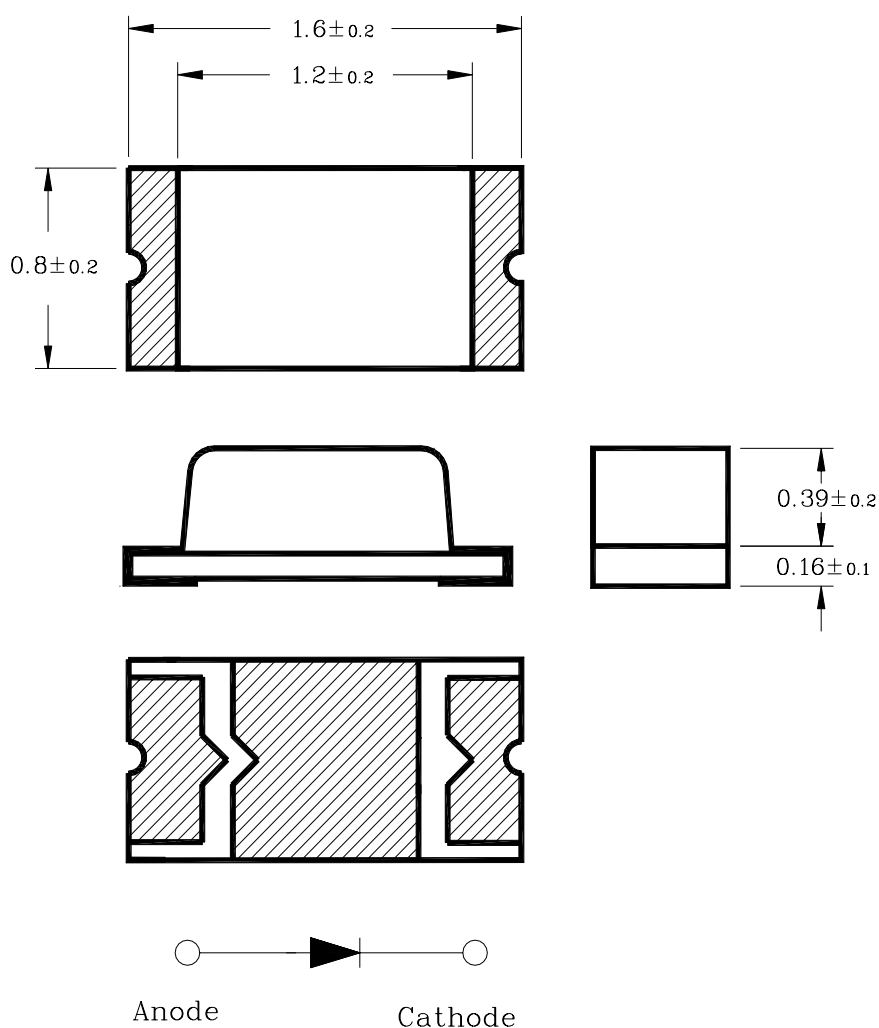


Features

- 1.6mm(L)×0.8mm small size surface mount type
- Thin package of 0.55mm(H) thickness
- Transparent clear lens optic
- Low power consumption type chip LED

Applications

- LCD backlighting
- Keypad backlighting
- Symbol backlighting
- Front panel indicator lamp

Outline Dimensions**unit : mm**

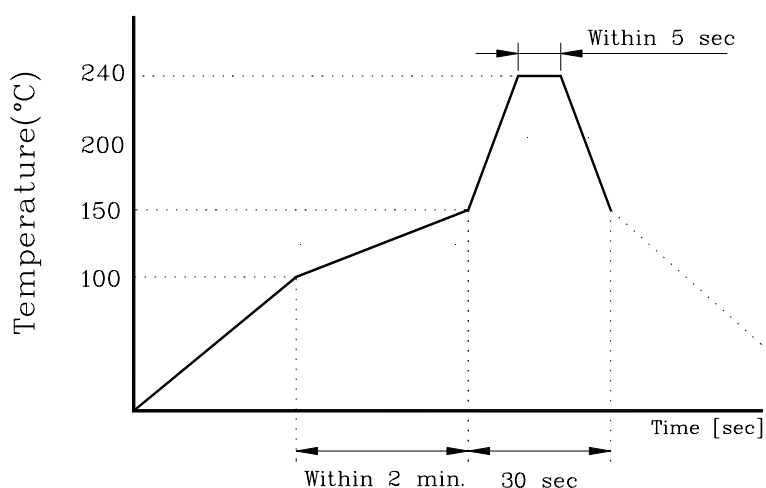
Absolute maximum ratings

Characteristic	Symbol	Ratings	Unit
Power Dissipation	P_D	70	mW
Forward Current	I_F	25	mA
* ¹ Peak Forward Current	I_{FP}	50	mA
Reverse Voltage	V_R	4	V
Operating Temperature	T_{opr}	-25 ~ 80	°C
Storage Temperature	T_{stg}	-30 ~ 100	°C
* ² Soldering Temperature	T_{sol}	240°C for 5 seconds	

*1. Duty ratio = 1/16, Pulse width = 0.1ms

*2. Recommended soldering Temperature Profile

2-1) Preheating 100°C to 150°C within 2 minutes Soldering 240°C within 5 seconds
Gradual cooling (Avoid quenching)



Electrical Characteristics

Characteristic	Symbol		Test Condition	Min	Typ	Max	Unit
Forward Voltage	V_F		$I_F = 20\text{mA}$	-	2.1	2.8	V
Luminous Intensity	I_V		$I_F = 20\text{mA}$	-	3	-	mcd
Peak Wavelength	λ_P		$I_F = 20\text{mA}$	-	557	-	nm
Spectrum Bandwidth	$\Delta \lambda$		$I_F = 20\text{mA}$	-	30	-	nm
Reverse Current	I_R		$V_R = 4\text{V}$	-	-	10	uA
Half angle	$\theta_{1/2}$	X	$I_F = 20\text{mA}$	-	± 65	-	deg
		Y		-	± 70	-	

Characteristic Diagrams

Fig. 1 $I_F - V_F$

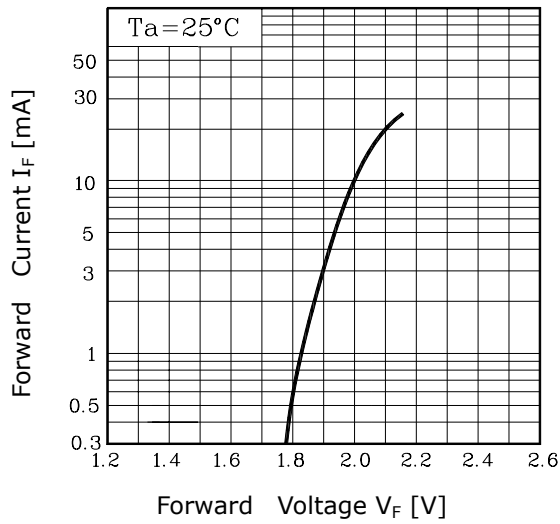


Fig. 2 $I_V - I_F$

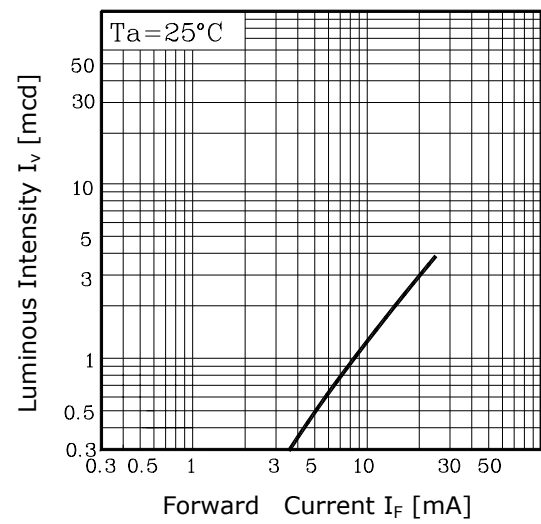


Fig. 3 $I_F - T_a$

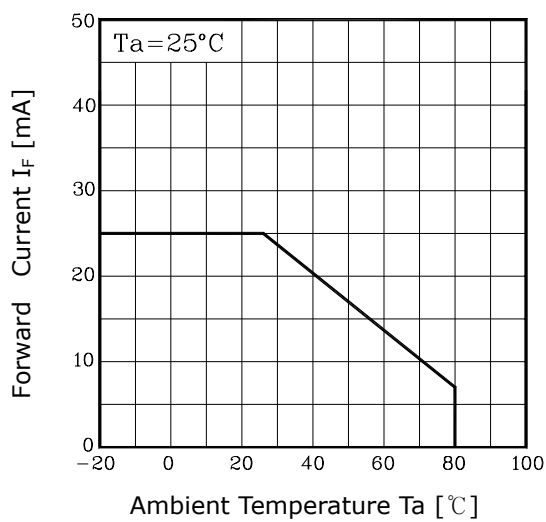


Fig.4 Spectrum Distribution

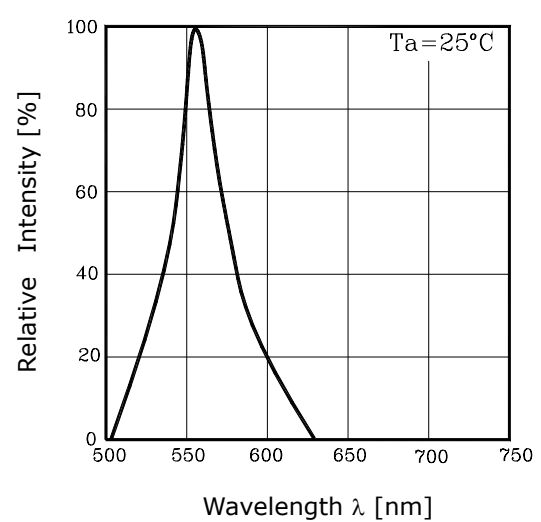


Fig. 5-1 Radiation Diagram(X)

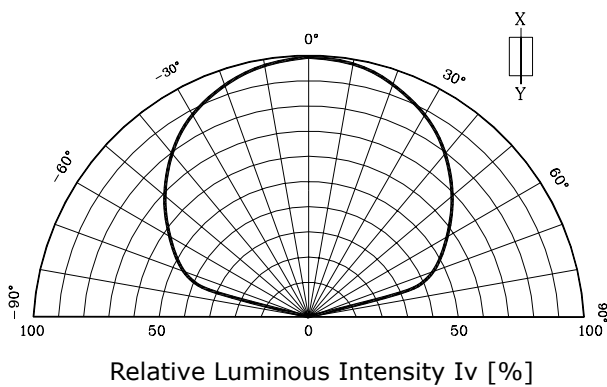


Fig. 5-2 Radiation Diagram(Y)

